



Article

Quantum Many-Body Theory for Exciton-Polaritons in Semiconductor Mie Resonators in the Non-Equilibrium

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Received: November 29, 2019; Accepted: March 02, 2020 Published: March 06, 2020

Abstract: We implement externally excited ZnO Mie resonators in a framework of a generalized Hubbard Hamiltonian to investigate the lifetimes of excitons and exciton-polaritons out of thermodynamical equilibrium. Our results are derived by a Floquet-Keldysh-Green's formalism with Dynamical Mean Field Theory (DMFT) and a second order iterative perturbation theory solver (IPT). We find that the Fano resonance which originates from coupling of the continuum of electronic density of states to the semiconductor Mie resonator yields polaritons with lifetimes between 0.6 ps and 1.45 ps. These results are compared to ZnO polariton lasers and to ZnO random lasers. We interpret the peaks of the exciton-polariton lifetimes in our results as a sign of gain narrowing which may lead to stable polariton lasing modes in the single excited ZnO Mie resonator. This form of gain may lead to polariton random lasing in an ensemble of ZnO Mie resonators in the non-equilibrium.

Keywords: Mie resonance, Fano resonance, Floquet modes, Stark effect, exciton, polariton, semiconductors, lasers, dynamical mean field theory, non-equilibrium

PACS: 42.55.-f lasers; 71.10.-w theories and models of many-electron systems; 42.50.Hz strong-field excitation of optical transitions in quantum systems; multi-photon processes; dynamic Stark shift; 74.40+ Fluctuations; 03.75.Lm Tunneling, Josephson effect, Bose-Einstein condensates in periodic potentials, solitons, vortices, and topological excitations; 72.20.Ht high-field and nonlinear effects; 71.36.+c polaritons; 71.35.-y excitons and related phenomena; 42.55.Px semiconductor lasers, laser diodes; 89.75.-k complex systems

0. Introduction

Semiconductor micro-cavities operating in the strong coupling regime are optical resonators in which the *eigenmodes* are no longer purely excitonic or photonic, but a mixed light matter state is occurring. This evolution has finally led to polariton lasing [1–9]. Random lasing [10] has been claimed to be fundamentally incompatible with polaritons. From recent research developments however it turns out that it is not yet clear whether random lasers are either pure photon lasers or pure polariton lasers, or whether they even have both characteristics at the same time [11]. Thresholds like in conventional lasers may be observed [12,13]. We show in this article that for excitations of the quantum many-body system of ZnO nano-resonators by experimentally feasible threshold intensities of the optical pump found in random laser experiments we derive theoretically well confined peaks in terms of gain narrowing in the spectrum of the

lifetime for the cavity polariton in the non-equilibrium. These peaks give evidence that such a sample may undergo a transition towards exciton-polariton lasing rather than a transition to exciton-photon lasing, at least a coexistence of both regimes may occur. ZnO is known for excellent light-matter coupling characteristics [7,14,15,23–34], it is predestined for this study. It has been experimentally derived that ZnO can be considered as a Mott insulator under certain conditions [23,25]. A feature of ZnO nano-structures is a transition from the non-centrosymmetric wurtzite structure to the centrosymmetric rocksalt configuration with a variation of temperature and pressure, see Fig. 1. When the system is externally pumped, Fig. 1(c), lasing may occur eventually. The propagating light intensity in the random laser may experience Mie resonances as a whispering gallery resonance of light at the inner surface of the individual nano-structure. In a complex medium, which pumped ZnO in the non-equilibrium certainly is, the resonant Mie mode forms a light matter bound state in the form of a Fano resonance. It leads to quantum many body physics and the renormalization of the bands under excitations. We consider (i) the semiconductor material as it is subjected to the strong external AC field of the optical pump in the sense of a topological excitation [14,15]. We model the coupling of the classical laser, $\hbar\Omega_L = 1.75 \text{ eV}$, to the quantum many body system as well as higher-order photon absorption processes, $\hbar\Omega_L = 3.5 \text{ eV}$ etc., by means of the Floquet matrix [40–43]. The band structure and the lifetimes of light-matter coupled states are derived by the Dynamical Mean Field Theory (DMFT) [44–47] in the sense of a generalized Hubbard-Hamiltonian out-of thermodynamical equilibrium. The Hubbard Hamiltonian includes strictly local interactions between electrons with opposite spins. It is predestined to describe the exciton dynamics of excited matter in a physical time range where additional impurity scattering is not expected. Bulk ZnO develops under excitation in the near band gap region an exciton dynamics. In the second step of this work (ii) we additionally consider photons which populate the Mie resonance of the individual nano-resonator and we study the formation of polaritons. The spectral features are compared to experimental emission spectra of ZnO random lasers and polariton lasers and we find a very good agreement in either case.

1. Theory

1.1. Hubbard Model for Excitons and Exciton-Polaritons

The interacting Hamiltonian for the complex driven semiconductor resonator can be written as follows

$$\begin{aligned}
 H = & \sum_{i,\sigma} \varepsilon_i c_{i,\sigma}^\dagger c_{i,\sigma} + \frac{U}{2} \sum_{i,\sigma} c_{i,\sigma}^\dagger c_{i,\sigma} c_{i,-\sigma}^\dagger c_{i,-\sigma} - t \sum_{\langle ij \rangle, \sigma} c_{i,\sigma}^\dagger c_{j,\sigma} \\
 & + i\vec{d} \cdot \vec{E}_0 \cos(\Omega_L \tau) \sum_{\langle ij \rangle, \sigma} \left(c_{i,\sigma}^\dagger c_{j,\sigma} - c_{j,\sigma}^\dagger c_{i,\sigma} \right) + \hbar\omega_0 a^\dagger a + g \sum_{i,\sigma} c_{i,\sigma}^\dagger c_{i,\sigma} (a^\dagger + a).
 \end{aligned} \tag{1}$$

The electrons are described as a tight binding model, see Fig. 2, where the splitting into valence and conduction band symmetrically to the Fermi level is included by means of the Coulomb interaction U , see Fig. 2(b). The ZnO gap assumes the value of 3.38 eV [23,24]. The first term in the Hamiltonian $\sum_{i,\sigma} \varepsilon_i c_{i,\sigma}^\dagger c_{i,\sigma}$ denotes the local onsite potential. The term $\frac{U}{2} \sum_{i,\sigma} c_{i,\sigma}^\dagger c_{i,\sigma} c_{i,-\sigma}^\dagger c_{i,-\sigma}$ is devoted to the onsite Coulomb interaction U between electrons with opposite spins. The third term $-t \sum_{\langle ij \rangle, \sigma} c_{i,\sigma}^\dagger c_{j,\sigma}$ is due to the hopping processes with the amplitude t between nearest neighbor sites. The classical external pumping is described in terms of the time dependent field \vec{E}_0 with the laser frequency Ω_L , and τ respectively. In the term $i\vec{d} \cdot \vec{E}_0 \cos(\Omega_L \tau) \sum_{\langle ij \rangle, \sigma} \left(c_{i,\sigma}^\dagger c_{j,\sigma} - c_{j,\sigma}^\dagger c_{i,\sigma} \right)$ is noted the renormalization of the hopping processes

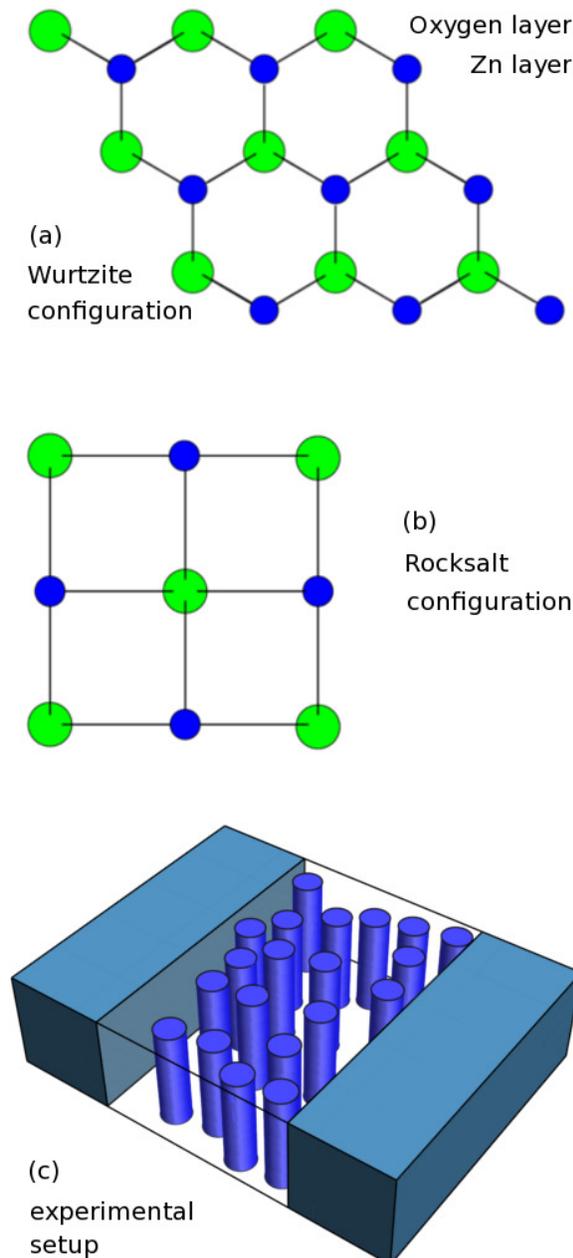


Figure 1. ZnO structure (ab-plane). **(a)** Non-centrosymmetric, hexagonal, wurtzite configuration **(b)** Centrosymmetric, cubic, rocksalt configuration (Rochelle salt) [29,32,33]. The rocksalt configuration is distinguished by a tunable gap from 1.8 eV up to 6.1 eV, a gap value of 3.38 eV is typical for the monocrystal rocksalt configuration without oxygen vacancies [30,31]. As such the rocksalt configuration could be suited for higher harmonics generation under non-equilibrium topological excitation [14,15,48]. **(c)** Typical setup of a solid state random laser: Densely packed disordered ZnO nano-resonators are embedded in a waveguide. The sample is externally pumped in (111) direction. Mie resonances [49] occur at the inner cylinder jacket and they couple to the density of bulk states in the sense of a Fano resonance. We consider in this article the exciton and exciton polariton dynamics of the single scatterer as the building block of the solid state random laser or the polariton random laser. Laser gain is attributed to the accumulation of excited states at a certain level along with a significantly increased life-time of the excited state, i.e. a stable laser in stationary state. In the random laser each scatterer of a well defined area or volume as part of an ensemble of several scatterers is going to lase. The investigation of the complex Mie-resonance in the non-equilibrium as the origin of pronounced laser levels for polariton lasing is on target. The formation of the polariton as a quasiparticle is characterized by the coupling strength $\gamma = g/t$ of the bulk electronic procedures and the cavity resonance which is on the order of the band width or one order below and thus it is in the polariton range [50]. The waveguide principally plays only a subordinate role, it does not serve as the dominating conventional laser resonator cavity.

due to interaction with the pump field. The electronic dipole operator \hat{d} is given with strength $|\vec{d}|$. The photonic cavity mode $\hbar\omega_0 a^\dagger a$ with the resonance frequency ω_0 is coupled to the electron system as $g \sum_{i,\sigma} c_{i,\sigma}^\dagger c_{i,\sigma} (a^\dagger + a)$ with a coupling strength g in units of the standard hopping t . The single band effective Hubbard model has been proven to be perfectly suited for the description of the movement of hole-bound electrons, excitons, as a quasiparticle through the lattice of metal ions [51–53], which is a lattice of Zn^{2+} ions here. For the solution of the Hamiltonian for driven bulk matter (i) as well as for the bulk-cavity coupled system (ii) including the fifth and the sixth term of Eq. (1), the explicit time dependence of the external field has to be accounted for as well as the dynamics of the system. It yields Green’s functions which depend on two separate time arguments. The double Fourier transform from time to frequency coordinates leads to two separate frequencies which are chosen as relative and center-of-mass frequency [42,43,46,47] and we can thus expand the underlying physical procedures into Floquet modes, the graphical explanation is found in Fig. 2(a),

$$\begin{aligned} G_{mn}^{\alpha\beta}(\omega) &= \int d\tau_1^\alpha d\tau_2^\beta e^{-i\Omega_L(m\tau_1^\alpha - n\tau_2^\beta)} e^{i\omega(\tau_1^\alpha - \tau_2^\beta)} G(\tau_1^\alpha, \tau_2^\beta) \\ &\equiv G^{\alpha\beta}(\omega - m\Omega_L, \omega - n\Omega_L). \end{aligned} \tag{2}$$

In Eq. (2) (m, n) label the Floquet modes and (α, β) label the branch of the Keldysh contour (\pm) where the respective time argument resides. Floquet modes in time-space an analogue to Bloch modes in real space. The physical meaning of the expansion into Floquet modes is however noteworthy, since it is the quantized absorption and emission of energy $\hbar\Omega_L$ out of and into the classical external driving field.

In case of uncorrelated electrons, $U = 0$, an analytical solution for the Green’s function $G_{mn}(k, \omega)$ is found by solving the Hamiltonian. The retarded component of $G_{mn}(k, \omega)$ is

$$G_{mn}^R(k, \omega) = \sum_\rho \frac{J_{\rho-m}(A_0 \tilde{\epsilon}_k) J_{\rho-n}(A_0 \tilde{\epsilon}_k)}{\omega - \rho\Omega_L - \epsilon_k + i0^+}. \tag{3}$$

$\tilde{\epsilon}_k$ represents the externally induced dispersion which is to be distinguished from the lattice dispersion ϵ_k . J_n are the cylindrical Bessel functions of integer order, $A_0 = \vec{d} \cdot \vec{E}_0$ and Ω_L characterize the external driving laser. The physical Green’s function for the optically excited band electron (LB) is derived

$$G_{\text{LB}}^R(k, \omega) = \sum_{m,n} G_{mn}^R(k, \omega). \tag{4}$$

1.2. Dynamical Mean-Field Theory for Electromagnetically Driven Semiconductors in $d=3$ Dimensions

The Hamiltonian for the correlated system, $U \neq 0$, Eq. (1), is solved numerically with a single-site Dynamical Mean Field Theory (DMFT) [45–47] and an iterated perturbation theory solver (IPT), see Fig. 2(f). The laser-band-electron Green’s function $G_{\text{LB}}^R(k, \omega)$, Eq. (4), is characterized by the wave vector k , describing the periodicity of the lattice, the electronic energy ω and the external driving frequency Ω as contained in the Floquet indices (m, n) . The DMFT self-consistency relation assumes the form of a 2×2 dimensional matrix equation in regular Keldysh space and in becomes $n \times n$ dimensional in Floquet space. The IPT is generalized to Keldysh-Floquet form as well. The resulting numerical algorithm proves to be efficient and stable for all values of U .

The coupling $\hat{d} \cdot \vec{E}_0 \cos(\Omega_L \tau)$ under the assumption of the Coulomb gauge $\vec{E}(\tau) = -\frac{\partial}{\partial \tau} \vec{A}(\tau)$, that is in Fourier space $\vec{E}(\Omega_L) = i\Omega_L \cdot \vec{A}(\Omega_L)$, generates the factor Ω_L that cancels the $1/\Omega_L$ term in the renormalized cylindrical Bessel function, for details see Eq. (7) of ref. [46]. By checking the Floquet sum

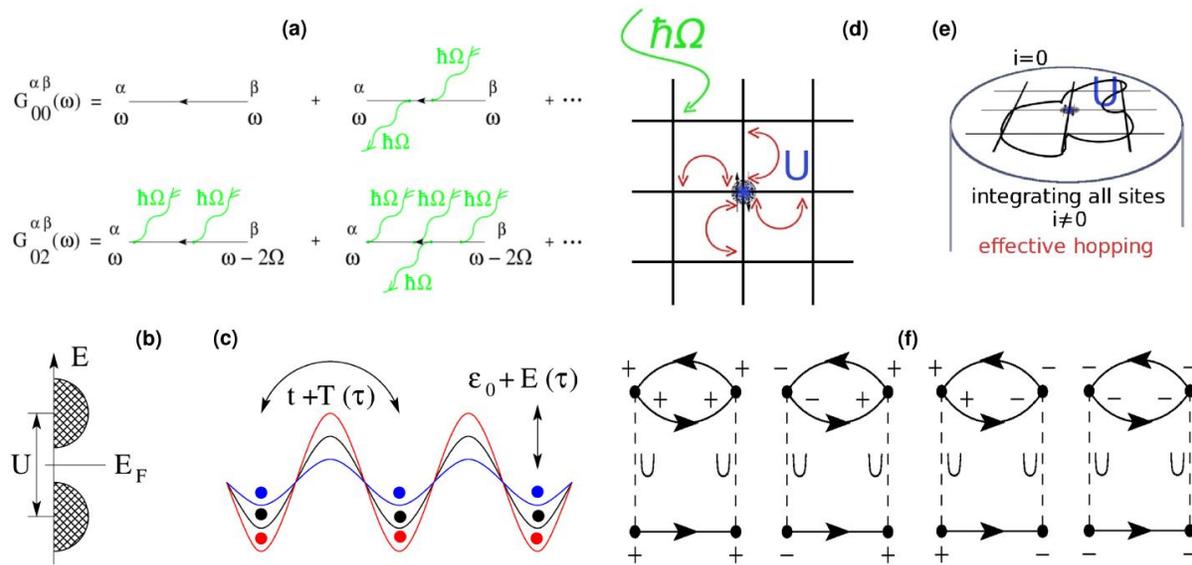


Figure 2. Theoretical setup (a) Floquet expansion of the Green’s function G into higher harmonics of $\hbar\Omega_L$. (b) Hubbard model of the electronic system. The gap between bands is defined by the Coulomb interaction U symmetrically to the Fermi Energy E_F . (c) Tight binding system of the crystal lattice. The hopping parameter t is renormalized by external time dependent excitations $T(\tau)$. $\epsilon_0 + E(\tau)$ are renormalizations of the local potential alone. (d) Non-equilibrium DMFT. Pump photons $\hbar\Omega_L$ enhance electronic hopping which is mapped on the single site on the background of the surrounding identical lattice sites, the bath. (e) Integration over all sites yields an effective self-consistent theory including non-equilibrium effects. The electronic system is coupled to Mie resonances. (f) Diagrammatic contributions of the second order IPT.

we find that considering the first ten ($n = 10$) Floquet modes is sufficient within the numerical accuracy of the DMFT [14,15]. A cut-off after a smaller number would lead to a drift in the total energy of the system and thus it would hurt conservation laws.

While the quasienergy spectra of excitons and the Franz-Keldysh effect in the non-equilibrium have been broadly investigated in $d=2$ dimensions for semiconductors in the THz regime, especially for GaAs [16–18], only recently the first numerical studies of the excitonic quasienergy spectra under topological excitations in the optical regime have been performed for ZnO with DMFT in $d=3$ dimensions [14,15]. Whereas DMFT has been so far preferentially used for typical Mott insulators [19] like NiO [20,21], this DMFT study [14,15] is remarkable, since ZnO as a wide-gapped transition metal oxide from the group IIb in the table of the elements which may be considered to behave as a Mott insulator at zero temperature [23,25], especially in driven nano-structures this is the case. ZnO is broadly investigated for random lasing in disordered ensembles of nano-pillars and nano-grains, i.e. Mie spheres, and a restriction to two-dimensional electronic processes is no necessary condition in these ensembles [10]. Two-dimensionality is *a priori* also not necessary for the considering the formation of polaritons [1].

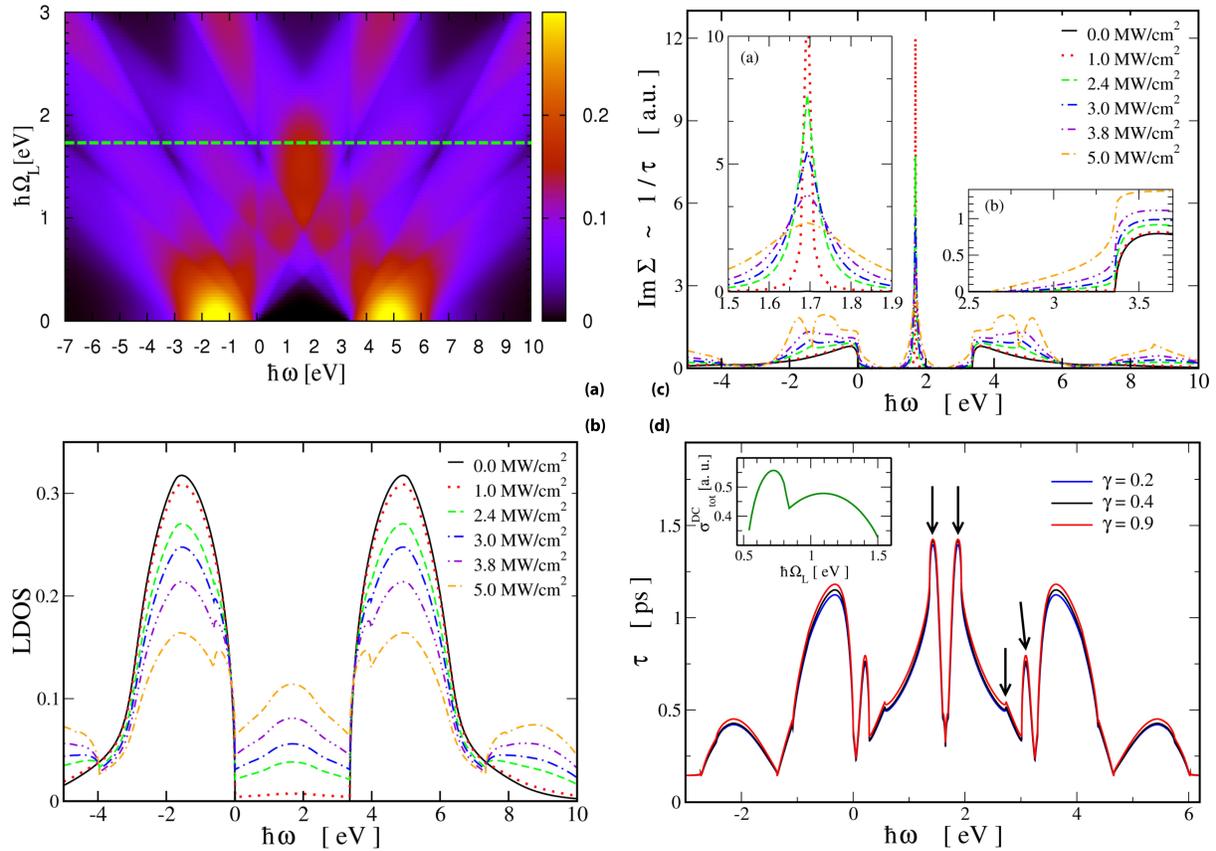


Figure 3. (a) LDOS of bulk ZnO for varying excitation laser frequency Ω_L . The electronic gap in equilibrium is 3.38eV , the microscopic dipole moment equals $|d| = 2.30826288 \times 10^{-28}\text{Cm}$, the lattice constant is $a = 0,325\text{nm}$. The excitation strength is $10.0\text{MW}/\text{cm}^2$. A multitude of Floquet bands and sub-gaps emerge due to the AC Stark effect. (b) Excitonic LDOS for the driving frequency if 1.75eV , with increasing intensity, 0 to $5.0\text{MW}/\text{cm}^2$. Spectral weight is shifted into the Floquet bands which cross in the gap region. Mid-gap states emerge. (c) Inverse excitonic lifetime $\text{Im}\Sigma, 1/\tau$, for parameters as in (b). (Inset a) The peak centered at 1.69eV indicates small lifetimes and a fast decay of mid-gap states (red line). (Inset b) The excitonic lifetime near the band edges is reduced but finite. With increasing pump intensity the near band-edge lifetime decreases but in comparison to the value in the band it is increased.(d) Lifetimes of exciton-polaritons in ZnO nano-pillars. Parameters are: pump wavelength $\lambda = 710\text{nm}$ (1.75eV), cavity resonance at $\lambda = 505.34\text{nm}$, (2.45eV , passive refractive index $n = 1.97182$) pump intensity $2.4\text{MW}/\text{cm}^2$. Sharp features at 0.05eV and $2.5..3.3\text{eV}$, ($\lambda = 495.94..375.71\text{nm}$) show gain narrowing. The increase of the coupling strength γ of bulk matter and cavity yields rather small effects. (Inset) The optical conductivity σ_{tot} for exciton-polaritons, $\gamma = 0.2$, in the THz regime in the non-equilibrium is finite.

2. Results

For driven ZnO bulk we display in Fig.3(a) the local density of excitonic states (LDOS) for $10.0\text{MW}/\text{cm}^2$ pump power and the varying external laser frequency Ω_L . The systems parameters are found in the caption of Fig. 3. A multitude of Floquet bands arises due to the AC Stark effect and sub-gaps are formed whereas the original gap closes. These results are computed for a cubic lattice structure and their physical interpretation besides the formation of exciton-quasiparticles is the generation of bands of

even higher harmonics due to the symmetry of the system. For the fixed value of $\hbar\Omega_L = 1.75 \text{ eV}$, Fig. 3(b), we find an increasing LDOS for excitons in the ZnO gap region. The solid black line indicates the undriven bandstructure with a half band width of 1.7 eV . In the valence and the conduction band sub gaps towards the near-gap band edges at -0.67 eV and 4.05 eV are formed, while at the inner band edges a step-like decrease is found. A smooth mid-gap feature is building up with increasing pump strength. In the results for the inverse lifetime, $1/\tau$, of excitons $\text{Im}\Sigma$, Fig. 3(c), which characterizes the dynamics of the excitons we find a sharp peak at the Fermi edge, i.e. small lifetimes of excitons as we expected it. $\text{Im}\Sigma$ is increasing in the gap near the equilibrium band edges. We find an increasing LDOS for excitons with the increase of the external excitation strength. The lifetimes of the near-edge states are therefore progressively decreased. A plateauing of exciton lifetimes is observed in the band gap otherwise, whereas deep in the band at e.g. 4.8 eV we find for increasing external pump intensity a crossover of the corresponding excitonic lifetimes. Here $1/\tau$ exhibits a local maximum around a pump intensity of $|E_0|^2 = 3.8 \text{ MW/cm}^2$ which then transforms with further increasing pump strength into a local minimum (orange dash-dotted line) and eventually reaches lifetimes almost as high as in the un-driven equilibrium system (black solid line). For the cavity coupled system, Fig. 3(d), we find a qualitatively different behavior. It should be noted first that the presence of the cavity also for the weakly coupled case in the non-equilibrium always has an influence on the full spectrum of the LDOS. This is necessarily the case for energy and particle conservation. The semiconductor pillars with a full diameter of $d = 260.0 \text{ nm}$ are chosen with a geometrical Mie resonance as a single whispering gallery mode on the inner jacket of the resonator. The coat thickness may vary with the fineness of the ZnO material. As such it may determine the Q-factor of the single Mie resonator in principle [22], however in the non-equilibrium regime and in the corresponding physical time range microscopic interactions in the sense of impurity scattering in the selvedge have no fundamental influence. The Mie resonance of $\hbar\omega_0 = 2.45 \text{ eV}$ corresponds to the wavelength $\lambda = 505.34 \text{ nm}$ [49], effectively this whispering gallery is populated in the resonance by photons. Thus the classical picture of the Mie resonance [38] of a sole geometric resonance of otherwise passive matter is replaced here by the Fano resonance [39] of the single mode with the continuum of excitons which is embedded in a Floquet matrix [40–43]. The Floquet matrix, see Fig. 2(a), represents mathematically the physics of high amplitude excitations and higher harmonics [48] under the presumption of energy conservation. We display the exciton-polariton lifetimes for $(g/t) = 0.2, 0.4, 0.9$ at zero temperature and at half filling. The coupling strength as such is characteristic for the formation of polaritons [50]. The results are derived for an external optical pump intensity of 2.4 MW/cm^2 which on the other side is a typical pump strength for solid state random lasers [35–37,54]. We find a sharp dip in the lifetimes of polaritonic states at the Fermi energy. In agreement with the results for the bulk we also find the characteristic features around the Fermi edge. The dip of $1/\tau$ at 4.8 eV for the driving intensity of 2.4 MW/cm^2 for bulk persists in the full cavity coupled system, Fig. 3(d). The magnitude of the exciton-polariton lifetimes in the marked features of gap states is 1.45 ps (for 1.4 eV and 1.9 eV), 0.6 ps (for 2.75 eV), and 0.75 ps (for 3.1 eV). The peak of the exciton-polariton lifetimes in the original band at 3.65 eV is derived as 1.25 ps . The peaks in the results for the polaritonic lifetime (black arrows in Fig. 3(d)) are all emerging quite far off from the cavity's resonance at $\lambda = 2.45 \text{ eV}$ which is a proof of the dynamic Fano coupling in the driven non-equilibrium system. The peaks can be interpreted as a splitting into several polariton branches which for the given parameters of random lasers may define the laser spectrum of a random polariton laser consisting of ZnO Mie resonators. The result for the optical DC-conductivity σ_{tot} as the materials characteristics in the non-equilibrium is displayed for $\gamma = 0.2$ in the inset of Fig. 3(d) in the THz region and the same parameters otherwise. σ_{tot} assumes a finite value. The pronounced minima in σ_{tot} are another signature of gain and gain narrowing in the full polaritonic spectrum. Our results of lifetimes of excitons and exciton-polaritons are corroborated by the experimental findings of laser spectra in several setups of ZnO Mie resonators as well as in ZnO random lasers [27,28,35–37,54,55] where in either experiment stable lasing modes at 3.13 eV have been

found. In either system the spectral result is attributed to the coupling of the excited electronic subsystem of ZnO bulk to the resonator mode of the single scatterer. Refs. [27,28,55] interpret their findings as exciton-polaritons.

3. Conclusions

We presented in this article results for the local density of states and the lifetimes of excitons and of exciton-polaritons in excited ZnO Mie resonators in the non-equilibrium. The sharp spectral features of the polaritonic lifetimes are in clear qualitative and quantitative contrast to the results for the exciton lifetimes. Furthermore they are in qualitative and in quantitative agreement with experimental results of ZnO polariton lasers on the one hand and on the other hand they also agree with results for the spectrum and the life times of solid state random lasers. We conclude that a random polariton laser can be built as an application of ZnO Mie resonators in the non-equilibrium.

Author Contributions: All authors contributed equally to this work. All authors wrote and reviewed the manuscript.

Acknowledgments: The authors thank H. Cao, P. Guyot-Sionnest, H. Kalt, A.-P. Jauho, M. Richard, J.K. Freericks and G. Kotliar for fruitful discussions.

References

1. Yamamoto, Y.; Half-matter, half-light amplifier, *Nature* **2000**, *405*, 629-630.
2. Imamoglu, A.; Ram, R. J.; Pau, S.; Yamamoto, Y.; Nonequilibrium condensates and lasers without inversion: Exciton-polariton lasers, *Phys. Rev. A* **1996**, *53*, 4250-4253.
3. Zamfirescu, M.; Kavokin, A.; Gil, B.; Malpuech, G.; Kaliteevski, M.; ZnO as a material mostly adapted for the realization of room-temperature polariton lasers, *Phys. Rev. B* **2002**, *65*, 161205(R).
4. Deng, H.; Weihs, G.; Santori, C.; Bloch, J.; Yamamoto, Y.; Condensation of semiconductor microcavity exciton polaritons, *Science* **2002**, *298*, 199-202.
5. Kasprzak, J.; Richard, M.; Kundermann, S.; Baas, A.; Jeambrun, P.; Keeling, J. M.; Marchetti, F. M.; Szymanska, M. H.; Andre, R.; Staehli, J. L.; Savona, V.; Littlewood, P. B.; Deveaud, B.; Dang, L. S.; Bose-Einstein condensation of exciton polaritons, *Nature* **2006**, *443*, 409-414.
6. Schneider, C.; Rahimi-Iman, A.; Kim, Y. N.; Fischer, J.; Savenko, I. G.; Amthor, M.; Lermer, M.; Wolf, A.; Worschech, L.; Kulakovskii, V. D.; Shelykh, I. A.; Kamp, M.; Reitzenstein, S.; Forchel, A.; Yamamoto, Y.; Höfling, S.; An electrically pumped polariton laser, *Nature* **2013**, *497*, 348-352.
7. F. Li, L. Orosz, O. Kamoun, S. Bouchoule, Ch. Brimont, P. Disseix, T. Guillet, X. Lafosse, M. Leroux, J. Leymarie, G. Malpuech, M. Mexis, M. Mihailovic, G. Patriarche, F. Reveret, D. Solnyshkov, J. Zuniga-Perez, Fabrication and characterization of a room-temperature ZnO polariton laser, *Appl. Phys. Lett.* **102**, 191118 (2013).
8. Guillet, T.; Mexis, M.; Levrat, J.; Rossbach, G.; Brimont, Ch.; Bretnon, T.; Gil, B.; Butte, R.; Grandjean, N.; Orosz, L.; Reveret, F.; Leymarie, J.; Zuniga-Perez, J.; Leroux, M.; Semond, F.; Bouchoule, S.; Polariton lasing in a hybrid bulk ZnO microcavity, *Appl. Phys. Lett.* **2011**, *99*, 161104.
9. Bajoni, D.; Polariton lasers. Hybrid light-matter lasers without inversion, *J. Phys. D: Appl. Phys.* **2012**, *45*, 313001.
10. Cao, H.; Zhao, Y. G.; Ho, S. T.; Seelig, E. W.; Wang, Q. H.; Chang, R. P. H.; Random Laser Action in Semiconductor Powder, *Phys. Rev. Lett.* **1999**, *82*, 11 2278.
11. Niyuki, R.; Fujiwara, H.; Nakamura, T.; Ishikawa, Y.; Koshizaki, N.; Tsuji, T.; Sasaki, K.; Double threshold behavior in a resonance-controlled ZnO random laser, *APL Photonics* **2017**, *2*, 036101.
12. Lu, T.-C.; Lai, Y.-Y.; Lan, Y.-P.; Huang, S.-W.; Chen, J.-R.; Wu, Y.-C.; Hsieh, W.-F.; Deng, H.; Room temperature polariton lasing vs. photon lasing in a ZnO-based hybrid microcavity, *Opt. Express* **2012**, *20*, 5530.
13. Kim, S.; Zhang, B.; Wang, Z.; Fischer, J.; Brodbeck, S.; Kamp, M.; Schneider, C.; Höfling, S.; Deng, H.; Coherent Polariton Laser, *Phys. Rev. X* **2016**, *6*, 011026.
14. Lubatsch, A.; Frank, R.; Evolution of Floquet Topological Quantum States in Driven Semiconductors, *Eur. Phys. J. B* **2019**, *92*: 215, 92 (9), doi:10.1140/epjb/e2019-100087-0.

15. Lubatsch, A.; Frank, R.; Behavior of Floquet Topological Quantum States in Optically Driven Semiconductors. *Symmetry* **2019**, *11*, 1246; doi: 10.3390/sym11101246.
16. Jauho, A.-P.; Johnsen, K.; Dynamical Franz-Keldysh Effect, *Phys. Rev. Lett.* **1996**, *76*, 24, 4576-4579.
17. Nordstrom, K.B.; Johnsen, K.; Allen, S.J.; Jauho, A.-P.; Birnir, B.; Kono, J.; Noda, T.; Akiyama, H.; Sakaki, H.; Excitonic Dynamical Franz-Keldysh Effect, *Phys. Rev. Lett.* **1998**, *81*, 2, 457-460.
18. Johnsen, K.; Jauho, A.-P.; Quasienergy Spectroscopy of Excitons, *Phys. Rev. Lett.* **1999**, *83*, 6, 1207-1210.
19. Savrasov, S. Y.; Kotliar, G.; Linear Response Calculations of Lattice Dynamics in Strongly Correlated Systems, *Phys. Rev. Lett.* **2003**, *90* (5) 056401-1.
20. Fiebig, M.; Fröhlich, D.; Lottermoser, Th.; Pavlov, V. V.; Pisarev, R. V.; Weber, H.-J.; , Second Harmonic Generation in the Centrosymmetric Antiferromagnet NiO, *Phys. Rev. Lett.* **2001**, *87* (13), 137202-1.
21. Castell, M. R.; Wincott, P. L.; Condon, N. G.; Muggelberg, C.; Thornton, G.; Dudarev, S. L.; Sutton, A. P.; Briggs, G. A. D.; Atomic-resolution STM of a system with strongly correlated electrons: NiO(001) surface structure and defect sites, *Phys. Rev. B* **1997**, *55* (12), 7859.
22. Gibbs, H. M.; Khitrova, G.; Koch, S. W.; Exciton-polariton light-semiconductor coupling effects. *Nat. Phot.* **2011**, *5*, 275-282.
23. Chang, P.-C.; Lu, J. G.; Temperature dependent conduction and UV induced metal-to-insulator transition in ZnO nanowires, *Appl. Phys. Lett.* **2008**, *92*, 212113.
24. Aghamalyan, N. R.; Aslanyan, T. A.; Vardanyan, E. S.; Kafadaryan, Y. A.; Hovsepian, R. K.; Petrosyan, S. I.; Poghosyan, A. R.; Metal-insulator electronic phase transitions in wide-gap ZnO semiconductors. *Journal of Contemporary Physics* (Armenian Academy of Sciences), **2012**, *47*, 6, 275-281.
25. Chang, P.-C.; Chien, C.-J.; Stichtenoth, D.; Ronning, C.; Lu, J. G.; Finite size effect in ZnO nanowires, *Appl. Phys. Lett.* **2007**, *90*, 113101.
26. Shimada, R.; Xie, J.; Avrutin, V.; Özgür, Ü.; Morkovic, H.; Cavity polaritons in ZnO-based hybrid microcavities, *Appl. Phys. Lett.* **2008**, *92*, 011127.
27. Dai, J.; Xu, C. X.; Sun, X. W.; Zhang, X. H.; Exciton-polariton microphotoluminescence and lasing from ZnO whispering-gallery mode microcavities, *Appl. Phys. Lett.* **2011**, *98*, 161110.
28. Duan, Q.; Xu, D.; Liu, W.; Lu, J.; Zhang, L.; Wang, J.; Wang, Y.; Gu, J.; Hu, T.; Xie, W.; Shen, X.; Chen, Z.; Polariton lasing of quasi-whispering gallery modes in a ZnO microwire, *Appl. Phys. Lett.* **2012**, *103*, 022103.
29. Razavi-Khosroshahi, H.; Edalati, K.; Wu, J.; Nakashima, Y.; Arita, M.; Ikoma, Y.; Sadakiyo, M.; Inagaki, Y.; Staykov, A.; Yamauchi, M.; Horita, Z.; Fuji, M.; High-pressure zinc oxide phase as visible-light-active photocatalyst with narrow band gap, *J. Mater. Chem. A*, **2017**, *5*, 20298-20303.
30. Huang, F.; Lin, Z.; Lin, W.; Zhang, J.; Ding, K.; Wang, Y.; Zheng, Q.; Zhan, Z.; Yan, F.; Chen, D.; Lv, P.; Wang, X.; Research progress in ZnO singlecrystal: Growth, scientific understanding, and device applications, *Chinese Science Bulletin* **2014**, *59*, 1235.
31. Park, W. I.; Jun, Y. H.; Jung, S. W.; Yi, G.-C.; Excitonic emissions observed in ZnO single crystal nanorods, *Appl. Phys. Lett.* **2003**, *82*, 6 964-966.
32. Fritsch, D.; Schmidt, H.; Grundmann, M.; Pseudopotential band structures of rocksalt MgO, ZnO, and Mg_{1-x}Zn_xO, *Appl. Phys. Lett.* **2006**, *88*, 134104.
33. Dixit, H.; Saniz, R.; Lamoen, D.; Partoens, B.; The quasiparticle band structure of zincblende and rocksalt ZnO, *J. Phys. Condens. Matter* **2010**, *22*, 125505.
34. Koster, R. S.; Changming, M. F.; Dijkstra, M.; van Blaaderen, A.; van Huis, M. A.; Stabilization of Rock Salt ZnO Nanocrystals by Low-Energy Surfaces and Mg Additions: A First-Principles Study, *J. Phys. Chem. C* **2015**, *119*, 5648-5656 doi: 10.1021/jp511503b.
35. Lubatsch, A.; Frank, R.; Coherent transport and symmetry breaking - laser dynamics of constrained granular matter, *New J. Phys.* **2014**, *16*, 083043.
36. Lubatsch, A.; Frank, R.; Tuning the Quantum Efficiency of Random Lasers - Intrinsic Stokes-Shift and Gain, *Scientific Reports* **2015**, *5*(1) 17000.
37. Lubatsch, A.; Frank, R.; A Self-Consistent Quantum Field Theory for Random Lasing, *Appl. Sci.* **2019**, *9*, 2477 doi:10.3390/app9122477.

38. Mie, G. Beiträge zur Optik trüber Medien, speziell kolloidaler Metallösungen, *Ann Phys. (Berlin)* **1908**, *4*, 25, 377-445.
39. Fano, U.; Effects of Configuration Interaction on Intensities and Phase Shifts, *Phys. Rev. A* **1961**, *124*, 1866.
40. Floquet, G. Sur les équations différentielles linéaires à coefficients périodiques. *Ann. l' Ecole Norm. Sup.* **1883**, *12*, 47-88.
41. Grifoni, M.; Hänggi, P. Driven quantum tunneling. *Phys. Rep.* **1998**, *304*, 229–354.
42. Frank, R. Coherent control of Floquet-mode dressed plasmon polaritons. *Phys. Rev. B* **2012**, *85*, 195463.
43. Frank, R. Non-equilibrium polaritonics - Nonlinear effects and optical switching. *Ann. Phys.* **2013**, *525*, 66–73.
44. Georges, A.; Kotliar, G.; Krauth, W.; Rozenberg, M.J. Dynamical mean-field theory of strongly correlated fermion systems and the limit of infinite dimensions. *Rev. Mod. Phys.* **1996**, *68*, 13.
45. Lubatsch, A.; Kroha, J. Optically driven Mott-Hubbard systems out of thermodynamical equilibrium. *Ann. Phys.* **2009**, *18*, 863–867.
46. Frank, R. Quantum criticality and population trapping of fermions by non-equilibrium lattice modulations. *New J. Phys.* **2013**, *15*, 123030.
47. Frank, R. Population trapping and inversion in ultracold Fermi gases by excitation of the optical lattice-Non-equilibrium Floquet - Keldysh description. *Appl. Phys. B* **2013**, *113*, 41–47.
48. Faisal, F.H.M.; Kaminski, J.Z. Floquet-Bloch theory of high-harmonic generation in periodic structures. *Phys. Rev. A* **1997**, *56*, 748.
49. Lubatsch, A.; Frank, R.; Self-consistent quantum field theory for the characterization of complex random media by short laser pulses, *Phys. Rev. Research* **2020**, <https://arxiv.org/abs/2001.02742> accepted, in press.
50. Forn-Diaz, P.; Lamata, L.; Rico, E.; Kono, J.; Solano, E.; Ultrastrong coupling regimes of light-matter interaction. *Rev. Mod. Phys.* **2019**, *91*, 025005-1.
51. Zhang, F. C.; Rice, T. M.; Effective Hamiltonian for the superconducting Cu oxides, *Phys. Rev. B* **1998**, *37*, 7, 3759.
52. Jarell, M.; Freericks, J.K.; Pruschke, Th.; Optical conductivity of the infinite-dimensional Hubbard model, *Phys. Rev. B* **1995**, *51*, 17, 11704.
53. Eder, R.; van den Brink, J.; Sawatzky, G. A.; Intersite Coulomb interaction and Heisenberg exchange, *Phys. Rev. B* **1996**, *54*, 2, R 732(R).
54. Kalt, H.; Fallert, J.; Dietz, R. J. B.; Sartor, J.; Schneider, D.; Klingshirn, C.; Random lasing in nanocrystalline ZnO powders, *Phys. Status Solidi B* **2010**, *247*, No. 6, 1448-1452.
55. Lai, Y.-Y.; Chou, Y.-H.; Lan, Y.-P.; Lu, T.-C.; Wang, S.-C.; Yamamoto, Y.; Crossover from polariton lasing to exciton lasing in a strongly couples ZnO microcavity *Scientific Reports*, **2015** *6*, 20581.

